Transmission electron microscopy structure and platinum-like temperature coefficient of resistance in a ruthenate-based thick film resistor with copper oxide

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As an alternative to thin-film platinum temperature sensor elements, thick film resistor ones are of interest for circuits which can withstand a near-engine environment. From a pyrochlore paste (DuPont 5091D), a close match is obtained (after firing) to the positive temperature coefficient of resistance (TCR) of Pt. Within the glassy matrix during 850 °C firing, needle-like RuO₂ grains grow by a mechanism consistent with periodic bond chain theory. The acicular growth habit is attributed to a Cu₂O additive, which is assumed to oxidize upon firing. The needles provide direct paths for metallic conduction and a characteristic positive TCR to the thick film in spite of having a low RuO₂ volume fraction. © 2000 American Institute of Physics. [S0021-8979(00)08414-0]

I. INTRODUCTION

Within the growing palette of thick film resistors, ones with platinum-like temperature coefficients of resistance (TCR) are of particular interest for automotive underhood applications. Not only can they be integrated in the same process for compact, multilayer, heat resisting circuitry, but they also can simplify temperature output linearization.

For the resistive temperature detection (RTD) thermometry applications, a large positive TCR is required, which is opposite to the goal of previous process-structure-property studies of low TCR resistors. Although fine Pt powders can be prepared as sinterable thick film pastes, such pastes require higher temperatures than normal 850 °C firing and designs with extremely high aspect ratio serpentines (or a thin film method), due to a low sheet resistance. Although PTCR (positive TCR) thick films have been prepared from non-noble pure metals (such as Ni) under protective atmospheres, they are subject to resistance drift due to oxidation in service.

For thick film resistors (TFR) with positive TCRs that are based on electronic conduction in air-stable oxides, the means are only described in a few citations. This literature points to three efforts, one with Ca–Cu–Ru–O compounds (with TCRs near 2000 ppm/K) and a second one with Cu₂O added to a Pb₂Ru₂O₆.₅-based pyrochlores (with some secant TCRs above 3000 ppm/K). The latter ones correspond to a recently introduced, conventionally firing PTCR paste, 5091D, which has no platinum. A third effort, with addition of copper oxides to a RuO₂-based TFR, increases the TCR, but only to near 1000 ppm/K.

In support of manufacturing circuits with a high TCR paste, some knowledge of processing-microstructure relationships is useful to aid in understanding the best ways to design, print, and fire the material. As before with the low TCR resistors, the investigation provides another interesting example of nanoscale composite electrical resistivity, as enhanced with a phase transformation observed during firing.

II. EXPERIMENT

Four probe layout designs were used with two internal probes of the self-same resistor material to exclude end effects. The present design has a smaller width (0.254 cm) and higher aspect ratio (8:1) than that used in low TCR resistor work (in Ref. 2, Fig. 4). Also provided were x-ray diffraction (XRD) pads (1 cm × 1.5 cm), which were also used for transmission electron microscopy (TEM). Quantities were sufficient to allow estimation of electrical property distributions.

The substrates used were 96% alumina, Coors AD-96 substrates of 0.635mm thickness and size 86 × 166 mm, with four images each per plate. The substrates were washed and dried prior to conductor printing.
TABLE I. Resistance vs temperature values as fitted to the three parameters of Eq. (1).

<table>
<thead>
<tr>
<th>( n )</th>
<th>Unit (count)</th>
<th>Central (inner probes)</th>
<th>Platinum comparison</th>
</tr>
</thead>
<tbody>
<tr>
<td>( R_0 \pm \sigma_R )</td>
<td>(( \Omega ))</td>
<td>96.66( \pm )9.09</td>
<td>18.39( \pm )0.40</td>
</tr>
<tr>
<td>( \alpha \pm \sigma_\alpha )</td>
<td>(ppm/K)</td>
<td>3796( \pm )36</td>
<td>3798( \pm )12</td>
</tr>
<tr>
<td>( \beta \pm \sigma_\beta )</td>
<td>(ppm/K(^2))</td>
<td>(-0.821\pm0.644)</td>
<td>(-0.99\pm0.21)</td>
</tr>
</tbody>
</table>

The conductor used was DuPont 7474F Ag–Pd alloy (nominally, 3Ag:1Pd) for low TCR interconnects. It is a physical mixture of fine Ag and Pd with some Bi\(_2\)O\(_3\), as determined by XRD. As it is fired at 850 °C for 10 min, it alloys to form a single phase of intermediate lattice constant.

The sheet resistance of the resistor paste used (DuPont 5091D, Lot IFH135) was nominally 10 \( \Omega \)/sq. As a paste (glass frit in an organic vehicle), its XRD is that of a pyrochlore indexed by Pb\(_2\)Ru\(_2\)O\(_{6.5}\) with ZrSiO\(_4\) and Cu\(_2\)O, with a broad background from glass. The paste was printed with a 325 mesh stainless steel screen with a 0.2 mm emulsion to an as-dried thickness of 24.3–25.7 \( \mu\)m.

A belt furnace thermal cycle was used that closely approximates the standard DuPont cycle with \( \sim \)10 min at peak temperature of 850 °C. After firing, the resistor thickness decreased to 14.9–16.3 \( \mu\)m (average 15.6 \( \mu\)m). No Cu\(_2\)O was detected by XRD.

For resistance measurements, test boards were mounted in a temperature-controlled chamber (Model 4248B, Saunders Associates, Scottsdale, AZ) and held for a minimum of 5 min with the chamber within 1 °C of target temperatures, in sequence: 25, \(-40, 125, 140, 100, \) and 150 °C. Four probe measurements were made using a system voltmeter. Fitting was done with Microsoft Excel to a quadratic TCR model, commonly used with Pt RTDs.

Cross-section and plan-view samples were prepared for TEM studies by cutting, mechanical grinding, polishing, dimpling, and low-angle Ar-ion milling to perforation. The survey studies were conducted with a JEOL 2000FX analytical electron microscope, operating at 200 kV, equipped with an x-ray energy-dispersive spectrometer (EDS). High-resolution TEM (HRTEM) was carried out with a JEOL 4000EX electron microscope operated at 400 kV (point resolution 0.17 nm) and equipped with a Gatan image Filter (GIF) system. HRTEM images were digitally recorded using a slow scan CCD camera.

III. RESULTS

A. Resistance and resistivity

Table I shows the \( R(T) \) data for the central interprobe section fit to a quadratic TCR model, as is typically used for platinum based RTDs:

\[
R(T) = R_0 (1 + \alpha T + \beta T^2),
\]

where \( T \) is temperature in °C and \( R_0 \) denotes resistance at 0 °C. For this quadratic fitting of individual thick film resistances [to the \( R(T) \) of Eq. (1) at six temperatures from \(-40 °C \) to \(+150 °C\)], typical Pearson correlation coefficients, \( R^2 \) (in the usual statistical notation), are about 0.99998. (Straight-line fitting typically gives lower correlation \( R^2 \) values, about 0.9999.) The platinum comparison in Table I is for thin film temperature sensing elements. In statistical \( t \) tests, neither the mean of the linear coefficient, \( \alpha \), nor the quadratic coefficient, \( \beta \), of the thick film resistors differed significantly (95% level) from those of the Pt elements.

Calculated from the average fired thickness of 15.6 \( \mu\)m, the resistivities of the thick film material in the central sections are: 0.0206\( \pm \)0.0019 \( \Omega \) cm at 25 °C and 0.0292\( \pm \)0.0027 \( \Omega \) cm at 150 °C.

B. Transmission electron microscopy characterization

Figure 1(a) is a bright-field TEM micrograph showing a representative microstructure of the ruthenate-based thick film resistor. Equiaxed particles and elongated grains (needles or fibers) are embedded in a matrix material ob-
served in Fig. 1(a). The width of most fibers is in the range from 10 to 80 nm, based on the examination of numerous micrographs from various areas.

The compositions of the matrix, equiaxed particles, and fibers in the specimen were determined by EDS analysis. Figures 1(b)–1(d) are EDS spectra taken from the matrix area (M), equiaxed particle (R), and fiber (F) in Fig. 1(a), respectively. An EDS spectrum taken from the matrix shows the presence of Pb, Bi, Gd, Al, Si, and O. The matrix is amorphous based on the electron diffraction analysis. EDS spectra taken from equiaxed particles show the presence of Ru, Pb, O, and Al. These equiaxed particles are, therefore, identified as the Pb$_2$Ru$_2$O$_6.5$ phase. The EDS spectrum taken from the fibers shows one intense Ru peak and other peaks from Al and O, which together indicate that the fiber is a Ru-rich compound.

In order to determine the crystallographic structure of the fibers in ruthenate-based thick film resistors, microbeam electron diffraction analysis was conducted. Figures 2(a)–2(c) are microbeam electron diffraction patterns from the same fiber for three different zone axes. Figure 2(b) was obtained by tilting the electron diffraction pattern of Fig. 2(a) around the PQ axis by 45°. Similarly, Fig. 2(c) was obtained by tilting the electron diffraction pattern of Fig. 2(a) around the UV axis by 51°. The angle between the two zone axes shown in Figs. 2(b) and 2(c) is 26°. That is to say, by tilting the electron diffraction pattern of Fig. 2(b) around the XY axis by 26°, we can obtain the diffraction pattern of Fig. 2(c). The angular relationship between the three zone axes is illustrated by the triangle in Fig. 2. Based on the diffraction pattern calculations, Figs. 2(a)–2(c) are the [100], [110], and [111] zone electron diffraction patterns, respectively, of RuO$_2$. Therefore, the crystal structure of the fiber is identified as the structure of RuO$_2$.

Figure 3(a) is a high-resolution TEM image of the profile of a part of a fiber showing a rounded-ended cap morphology. This image shows a round ended, rough interface, consisting of ledges and steps. In order to image high quality high-resolution TEM micrographs, it is known that the area of the specimen for imaging is preferred to be less than 10nm thick. The thin fiber [in Fig. 3(a)] keeps the same width over the 200 nm length and lies parallel within this thin TEM specimen. Therefore, the round-end-cap morphology shown in Fig. 3(d) does represents the profile of the fiber end (rather than the end of a section). Accordingly, the fibers in these ruthenate-based thick film resistors are concluded to have a nearly spherical cap morphology. This conclusion can also
provided which are attachment/growth sites to adsorb the adatoms. The growth in the [001] direction will be governed by the mass transport through the glass matrix. (By the time the thick film composite reaches the 850 °C firing temperature, the Ru-containing oxide particles are entirely encapsulated within a glassy matrix. Consequently, no gas phase is adjacent to the growing needles in which any volatile species might move.) In contrast, the (110) interface consisting of Ru and O atoms is a flat plane and is close packed, as illustrated in Fig. 4(c). The (110) plane of RuO$_2$, together with its equivalent (1T0), (T10), and (1T1) planes, form four flat interfaces between the fiber and the amorphous matrix. There are no attachment/growth sites in such a flat interface to permit adsorption of adatoms. The growth of the flat interface along the [110] and [1T0] directions is governed by a layer-to-layer two-dimensional plane growth mode, which is controlled by the interfacial nucleation and diffusion. Consequently, the growth rate in the [001] direction (length) of the fiber is much higher than that in [110] direction (width).

X-ray powder diffraction pattern analyses show that the small amount of Cu$_2$O phase existing in the ruthenate-based resistor pastes disappears after firing. It may be presumed that, upon firing, the Cu$_2$O phase in the precursor paste oxidizes to CuO, which then dissolves in the glass. Figure 4(d) shows the (1T1) plane of CuO. CuO has a monoclinic structure$^{13}$ with lattice parameters: $a_{\text{CuO}}=4.653$ Å, $b_{\text{CuO}}=3.41$ Å, $c_{\text{CuO}}=5.108$ Å, and $\beta=99^\circ29'$. The size of the rectangular unit in the (1T1) plane of CuO in Fig. 4(d) is 6.3 Å × 3.41 Å. These values are close in size to that of the rectangular unit in the (110) plane of RuO$_2$ at 6.35 Å × 3.11 Å, as shown in Fig. 4(c). Therefore, the (11T) plane of CuO is nearly lattice matched to the (110) plane of RuO$_2$ for a specific orientation relationship of RuO$_2$-[001]||CuO-[010] and RuO$_2$-[110]||CuO-[01T]. It is possible that during the growth of the fibers, (110) flat interfaces of RuO$_2$ may be covered by one (11T) CuO monolayer. As shown in Fig. 3(c), structural differences between the outermost monolayer and the inner layers of the fiber near the interface, may be considered as support of this model. The interfacial CuO monolayer would slow the growth of the RuO$_2$ fiber along the [110] and [1T0] directions, but have little influence on the growth in the [001] direction.

A. Microscopic composition and crystallography

The growth mechanism of the RuO$_2$ fibers can be understood using periodic bond chain (PBC) theory.$^{11}$ It is known$^{12}$ that RuO$_2$ is a tetragonal phase with the space group P4$_2$/mmm and lattice parameters: $a=4.49$ Å and $c=3.11$ Å. The PBC vectors in RuO$_2$ can be considered to lie along the [110], [1T0], and [001] directions. The Ru–O chain on the (002) plane is rotated 90° around the [001] axis with respect to that on the adjacent (001) planes, as shown in Figs. 4(a) and 4(b). Specifically, the Ru–O chain on the (002) plane is oriented along the [110] direction of RuO$_2$, whereas that on the (001) is oriented along the [1T0] direction. Therefore, the (001) interface is rough and has many steps naturally be supported by the additional fiber end images shown in Fig. 1(a).

Based on the morphology of the RuO$_2$ square cross-section particle (marked by letter “S”) in Fig. 1(a), the cross-sectional shape of the fibers can be deduced to be a square. The edges of the square section are inferred to be parallel to the [110] and [1T0] directions of RuO$_2$. Therefore, the three-dimensional morphology of the fiber is a square pole with a long axis parallel to the [001] axis of RuO$_2$ and with faces parallel to the (110) and (1T0) planes.

IV. DISCUSSION

The needle-like microstructure differs from the equiaxed pyrochlore particles of low TCR pastes that were previously studied.$^{23}$ This acicular structure shifts the larger contribution for electrical resistance in the composite to the metallic phase and, therefore, produces a highly positive TCR.

| TABLE I |

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B. Resistance and resistivity

The similarity to Pt of the fitted parameters (Table I) of the quadratic ($T,T^2$) model of Eq. (1) is of practical importance as this suggests the possibility of direct substitution with existing circuit calibrations.

In prior work$^2$ with near-zero TCR resistors, it had been shown that a ($T,1/T$)-fit was a better match to experimental data. The physical basis of the ($T,1/T$)-fit is the two-phase resistance model.$^{14}$ In the present work, the high aspect ratios of the RuO$_2$ needles provide straight metallic conduction bypass routes to any parallel routes through nonreacted, equiaxed Pb$_2$Ru$_2$O$_{6.5}$ particles and glass interfaces. Because of the high aspect ratios, the needles make the resistance
contribution in the overall composite from interparticle tunneling barriers an insignificant share of the measured resistance, as observed down to cryogenic temperatures.\textsuperscript{6} Thus, only the metallic terms in Eq. (8) of Ref. 14 are included, which correspond to the constant and linear terms in the quadratic fit. The quadratic term is small but concave downward. Force fitting of the two phase resistance model\textsuperscript{14} gives quadratic fit. The quadratic term is small but concave downward—which correspond to the constant and linear terms in the 

C. Role of morphology on TCR

The observed needle-like microstructure differs from the equiaxed ones of low-TCR ruthenate\textsuperscript{2,3} thick films that remain rhenuthenes. The transformation to a needle-like morphology is essential to obtain the metal-like magnitudes of positive TCR.

In the present PTCR material, some of the rhenenate decomposes to RuO\textsubscript{2} and PbO (which dissolves in the glass). The decomposition of the ruthenate depends on glass chemistry,\textsuperscript{8,15} and is enhanced by a lower initial concentration of PbO in the glass frit.\textsuperscript{16} With the transformation, elongated thin plates of RuO\textsubscript{2} have been observed.\textsuperscript{16} It was noted (Column 3, Lines 49–50 of Ref. 8) that the high TCRs are not achieved for the compositions that are produced from RuO\textsubscript{2} powders. Due to surface energy considerations, RuO\textsubscript{2} powders cannot "coarsen" into high aspect ratio shapes. With the transformation from rhenenate to RuO\textsubscript{2} (plus dissolved PbO), high specific surface area fiber growth becomes possible.

Experimentally, the addition of copper as oxide is known (Table VI, Ref. 9) to be critical to obtaining the higher TCRs. The explanation previously given ("interaction of the conductive phase with the glassy matrix")\textsuperscript{6} is rather vague. In the present samples, Cu\textsubscript{2}O (detected by XRD in the paste mixture) is oxidized during air firing to CuO, which dissolves in the glassy matrix. As described above, CuO has a specific crystallographic relationship which assists in the growth of the RuO\textsubscript{2} in a fiber morphology. In this fiber shape, the composite conductivity is that of the long axis of the needles, the RuO\textsubscript{2} [001] direction. Columns of atoms of Ru are then aligned to provide a metal-like conduction mechanism which leads to a highly positive, metal-like temperature coefficient of resistance.

V. CONCLUSIONS

The positive TCR thick film resistor differs from low TCR pastes, in that the DuPont 5091 pyrochlore in the paste partially transforms during firing to needle-like RuO\textsubscript{2} grains, rather than only coarsening.

Lattice-matched CuO monolayers on the (110) RuO\textsubscript{2} surfaces may help form the atomistically flat needle faces and lead to such high aspect ratio needles. High resolution TEM shows that the growth ends are rounded, consistent with periodic bond chain theory.

The close match of TCR may allow substitution for Pt-based thick films, with lower cost (due to the low volume fraction of needles needed for continuous path formation) and better oxidation resistance than with thick film resistors based on non-noble metals, such as Ni.

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